

Simple Physical Picture of the Overhauser Screened Electron-Electron Interaction

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As shown by Overhauser and others, the pair-distribution function $g(r)$ of a many-electron system may be found by solving a two-electron scattering problem with an effective screened electron-electron repulsion $V(r)$. We propose a simple physical picture in which this screened repulsion is the “dressed-dressed” interaction between two neutral objects, each an electron surrounded by its full-coupling exchange-correlation hole. For the effective interaction between two electrons of antiparallel spin in a high-density uniform electron gas of arbitrary spin polarization, we confirm that this picture is qualitatively correct. In contrast, the “bare-dressed” interaction is too repulsive, and does not have the expected symmetry $V_{\uparrow\downarrow}(r) = V_{\downarrow\uparrow}(r)$. The simple original Overhauser model interaction, independent of the relative spin polarization ζ , does not capture the ζ -dependence of the correlation contribution to $g(r=0)$.

The quantum mechanical many-electron problem is notoriously hard if all its degrees of freedom are taken into account. For both practical computational and conceptual purposes, however, it can often be replaced by a one- or two-electron problem with an effective external potential or electron-electron interaction, respectively. The effective potential that shapes the orbitals of the one-electron problem in Kohn-Sham density functional theory^{1,2} has been intensively explored, but the effective screened interaction that shapes the geminals of the two-electron problem^{3,4,5,6,7,8} has received less attention. Here we propose and provide some support for a physically-appealing “dressed-dressed” picture based upon the interaction between two neutral objects, each being an electron dressed by its surrounding exchange-correlation hole. In this picture, the “bare-bare” Coulomb repulsion $1/r$ is strongly screened out over the Wigner-Seitz radius r_s .

Overhauser⁷ showed that the singlet geminals of an effective two-electron scattering problem can be used to estimate the on-top pair-distribution function $g(0)$ in a spin-unpolarized ($\zeta = 0$) three-dimensional electron gas of uniform density

$$\bar{n} = 3/4\pi r_s^3. \quad (1)$$

(We use Hartree atomic units where $\hbar = m = e^2 = 1$.) Overhauser used an effective “bare-dressed” interaction between a bare electron and a neutral object composed of another electron and a concentric sphere of positive background charge of density \bar{n} and radius r_s . Gori-Giorgi and Perdew^{9,10} used the same effective interaction, but solved the Overhauser model exactly and found a pair-distribution function $g(r)$ in close agreement with that of Quantum Monte Carlo calculations over the whole short-range region $r \lesssim r_s$, for the physical density regime $1 \lesssim r_s \lesssim 10$. For the high-density ($r_s \rightarrow 0$) limit, they found good agreement with the exact^{11,12} $g(r)$ to order r_s . Since then, there have been many related studies for the three- or two-dimensional electron gas,^{13,14,15,16,17}

sometimes using constructions of self-consistent effective interactions following the general “bare-dressed” picture of Overhauser.^{3,7} Sum rules for the scattering phase shifts have also been derived.¹⁸

In this work, we consider a three-dimensional uniform electron gas with relative spin polarization

$$\zeta = (\bar{n}_{\uparrow} - \bar{n}_{\downarrow})/\bar{n}, \quad (2)$$

where $\bar{n} = \bar{n}_{\uparrow} + \bar{n}_{\downarrow}$ is the total density of Eq. (1). The pair-distribution function is then

$$g(r) = \left(\frac{1+\zeta}{2}\right)^2 g_{\uparrow\uparrow}(r) + \left(\frac{1-\zeta}{2}\right)^2 g_{\downarrow\downarrow}(r) + \frac{(1-\zeta^2)}{2} g_{\uparrow\downarrow}(r), \quad (3)$$

where only $g_{\uparrow\downarrow}$ contributes at $r = 0$ because of the Pauli principle. $\bar{n}g(r)$ is the average density of electrons at r when an electron is at the origin, and $\bar{n}[g(r) - 1]$ is the density of the exchange-correlation hole at full coupling strength, which carries a charge equal and opposite to that of the electron it surrounds:¹⁰

$$\int_0^\infty dr 4\pi r^2 \bar{n}[g(r) - 1] = -1, \quad (4)$$

with the same equation for $\bar{n}_{\uparrow}[g_{\uparrow\uparrow}(r) - 1]$ and $\bar{n}_{\downarrow}[g_{\downarrow\downarrow}(r) - 1]$. We focus on the effective interaction $V_{\uparrow\downarrow}(r)$ between two electrons of opposite spin in the high-density ($r_s \rightarrow 0$) limit, since in this case correlation can be neglected and the interaction is purely electrostatic. Thus we can evaluate the “bare-dressed” and “dressed-dressed” models exactly and compare the predictions of both to the exact pair-distribution function^{11,12,19} whose short-ranged part is dominated by $V_{\uparrow\downarrow}(r)$. We do not explicitly discuss the electron-electron scattering effects on transport properties, which are a second important application of the effective two-electron problem.^{3,4,6,17} We note however that the expected symmetry $V_{\uparrow\downarrow} = V_{\downarrow\uparrow}$ of the effective interaction for $\zeta \neq 0$ is only achieved by the “dressed-dressed” picture, not by the “bare-dressed” one.

Spin-unpolarized gas– In the Overhauser approach^{7,9} to electronic correlation in the unpolarized ($\zeta = 0$) uniform gas, the many-electron problem is reduced to a scattering event between two electrons in a suitable effective potential $V(r, r_s)$, with a corresponding radial Schrödinger equation:

$$\left[\frac{d^2}{dr^2} - \frac{\ell(\ell+1)}{r^2} - V(r, r_s) + k^2 \right] u_\ell = 0, \quad u_\ell = kr R_\ell(r, k, r_s). \quad (5)$$

The presence of the other electrons is taken into account in two ways: (i) via $V(r, r_s)$, (ii) via an average over the possible relative momentum $k = \frac{1}{2}|\mathbf{k}_1 - \mathbf{k}_2|$ of the scattering event. The exchange symmetry between the two electrons is ensured via a proper summation over the partial waves ℓ ; the resulting spin-resolved pair-distribution functions are then⁹

$$g_{\uparrow\downarrow}(r, r_s) = \left\langle \sum_{\ell=0}^{\infty} (2\ell+1) R_\ell^2(r, k, r_s) \right\rangle, \quad (6)$$

$$g_{\uparrow\uparrow}(r, r_s) = 2 \left\langle \sum_{\substack{\ell=1 \\ \text{odd } \ell}}^{\infty} (2\ell+1) R_\ell^2(r, k, r_s) \right\rangle, \quad (7)$$

where the symbol $\langle \dots \rangle$ denotes the average over the probability $p(k)$ (obtained from the momentum distribution of the ideal Fermi gas⁹). Overhauser's original choice⁷ for $V(r, r_s)$ was the potential of an electron surrounded by a Wigner-Seitz sphere of uniformly distributed positive charge:

$$V(r, r_s) = \begin{cases} \frac{1}{r_s} \left(\frac{1}{s} + \frac{s^2}{2} - \frac{3}{2} \right) & (r \leq r_s) \\ 0 & (r > r_s), \end{cases} \quad (8)$$

where

$$s = r/r_s \quad (9)$$

is a scaled variable. As said, this simple potential gave surprisingly accurate results⁹ for the short-range ($r \lesssim r_s$) part of the unpolarized-gas $g(r)$, at metallic and lower electron densities. The result for the high-density ($r_s \rightarrow 0$) limit was also quite accurate: the form of the screened Overhauser potential ensures that the correction to the noninteracting gas for $r_s \rightarrow 0$ is of first order in r_s , as in the exact perturbative result:¹¹

$$g_{\sigma\sigma'}(s, r_s \rightarrow 0) = g_{\sigma\sigma'}^{(0)}(s) + r_s g_{\sigma\sigma'}^{(1)}(s) + o(r_s), \quad (10)$$

where $g^{(0)}$ is the pair-distribution function of the noninteracting gas. (Eq. (10) is valid for $r \ll \sqrt{r_s}$.) In particular, for the value of the $\uparrow\downarrow$ pair-correlation function at contact ($r = 0$), the solution of the Overhauser model gives⁹ $g_{\uparrow\downarrow}(r = 0, r_s \rightarrow 0) = 1 - 0.694 r_s + o(r_s)$, in reasonable agreement with the exact result¹² $1 - 0.732 r_s + o(r_s)$. Nagy *et al.*¹⁷ have shown that the high-density form $g_{\uparrow\downarrow}(r = 0, r_s \rightarrow 0) = 1 - \lambda r_s + o(r_s)$ is guaranteed when

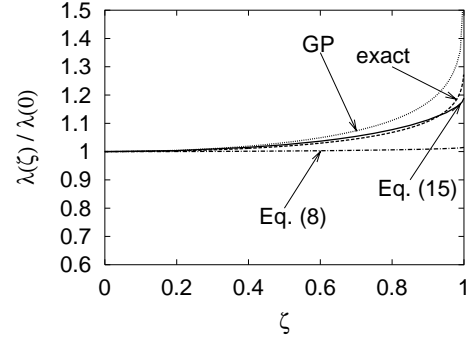


FIG. 1: ζ dependence of the high-density ($r_s \rightarrow 0$) correction to the on-top value $\lambda(\zeta)/\lambda(0)$ [see Eq. (12)]. The result from the “dressed-dressed” potential of Eq. (15) is compared with the exact calculation,^{11,19} with the result obtained from the original Overhauser potential of Eq. (8), and with the scaling relation proposed in Ref. 9 (GP).

Eqs. (5)-(7) employ a screened potential with screening length $\propto r_s$. For finite r , the $r_s \rightarrow 0$ form of Eq. (10) is satisfied, within the Overhauser approach, if the potential $V(r, r_s)$ is such that

$$V(r, r_s \rightarrow 0) = \frac{1}{r_s} U(s). \quad (11)$$

The Overhauser potential of Eq. (8) fulfills Eq. (11) at all r_s .

Spin-polarized gas – In the original formulation of the Overhauser model,⁷ information on the spin polarization state of the electron gas only enters through the probability distribution for the relative momentum k . The potential, purely based on classical electrostatic arguments, is independent of ζ . The probability functions $p_\zeta^{\sigma\sigma'}(k)$ are given in Eqs. (42)-(44) of Ref. 9, where, however, the calculations for the Overhauser model with $\zeta \neq 0$ have not been carried out. Instead, a scaling relation has been proposed.

Here, we carry out the calculations for the high-density limit with the correct $p_\zeta^{\uparrow\downarrow}(k)$, and we find a very weak ζ dependence of the first-order correction $\lambda(\zeta)$ to the on-top value,

$$g_{\uparrow\downarrow}(r = 0, r_s \rightarrow 0, \zeta) = 1 - \lambda(\zeta) r_s + o(r_s), \quad (12)$$

as shown in Fig. 1. This is due to the weak⁷ k dependence of the short-range part of the s -wave radial wavefunction $R_0(r \rightarrow 0, k, r_s)$ of Eq. (5). An explicit dependence on ζ in the effective potential is thus needed in order to reproduce the correct behavior^{11,19} of the short-range part of $g(r)$ in the spin-polarized electron gas. Moreno and Marinescu¹⁶ have recently applied the Overhauser model to the two-dimensional electron gas, finding an extremely weak ζ dependence of the on-top value. Our Fig. 1 suggests that their result could be an artifact of their ζ -independent effective interaction.

Effective interaction for opposite-spin electrons – In the high-density limit, a simple physically-motivated ef-

fective potential for antiparallel-spin interactions, which depends on ζ and has the symmetry $\uparrow\downarrow=\downarrow\uparrow$, can be obtained in the following way. Consider two electrons of opposite spin in a uniform electron gas in the high-density limit. Each electron induces around itself an exchange hole, forming a neutral object. The effective potential can be approximated with the electrostatic interaction between two neutral or “dressed” objects. When $\zeta = 0$, each electron is surrounded by a compact exchange hole, leading to effective screening of the Coulomb repulsion. But as ζ approaches 1, the exchange hole around the minority spin will become shallow and broad, so the Coulomb repulsion will be less well screened.

The two charge distributions are then

$$\rho_1(\mathbf{x}) = \delta(\mathbf{x}) + \bar{n}_\uparrow[g_x^{\uparrow\uparrow}(\mathbf{x}) - 1] \quad (13)$$

$$\rho_2(\mathbf{x}) = \delta(\mathbf{x} - \mathbf{r}) + \bar{n}_\downarrow[g_x^{\downarrow\downarrow}(\mathbf{x} - \mathbf{r}) - 1], \quad (14)$$

and the corresponding electrostatic potential is given by

$$V(r, r_s, \zeta) = \int d\mathbf{x} \int d\mathbf{x}' \frac{\rho_1(\mathbf{x})\rho_2(\mathbf{x}')}{|\mathbf{x} - \mathbf{x}'|}. \quad (15)$$

$V(r, r_s, \zeta)$ can be computed analytically: its Fourier transform $\tilde{V}(k, r_s, \zeta)$ is equal to

$$\tilde{V}(k, r_s, \zeta) = \frac{4\pi}{k^2} + v_1(k, r_s, \zeta) + v_2(k, r_s, \zeta) + v_3(k, r_s, \zeta),$$

with

$$v_1 = [S_x^{\uparrow\uparrow}(k, r_s, \zeta) - 1] \frac{4\pi}{k^2} \quad (16)$$

$$v_2 = [S_x^{\downarrow\downarrow}(k, r_s, \zeta) - 1] \frac{4\pi}{k^2} \quad (17)$$

$$v_3 = [S_x^{\uparrow\uparrow}(k, r_s, \zeta) - 1][S_x^{\downarrow\downarrow}(k, r_s, \zeta) - 1] \frac{4\pi}{k^2}, \quad (18)$$

where $S_x^{\sigma\sigma}$ are the exchange-only static structure factors,

$$S_x^{\sigma\sigma} = \begin{cases} \frac{3}{4} \frac{k}{k_F^\sigma} - \frac{1}{16} \left(\frac{k}{k_F^\sigma} \right)^3 & (k \leq 2k_F^\sigma) \\ 1 & (k > 2k_F^\sigma), \end{cases} \quad (19)$$

with $k_F^\sigma = (1 + \text{sgn}(\sigma)\zeta)^{1/3}k_F$, $k_F = (\frac{9\pi}{4})^{1/3}r_s^{-1}$, and $\text{sgn}(\sigma) = +1$ for spin- \uparrow and -1 for spin- \downarrow electrons. The exchange-only pair-distribution function g_x only depends on r_s through the scaled variable $s = r/r_s$. This ensures that $V(r, r_s, \zeta) = \frac{1}{r_s}U(s, \zeta)$, as required by Eq. (11). The dimensionless potential $U(s, \zeta)$ is screened for $s \gtrsim 1$, and goes to zero, when $s \rightarrow \infty$, as s^{-4} . Its ζ dependence is the one expected from the qualitative arguments given above, as shown in Fig. 2: when $\zeta \rightarrow 1$ the potential is less and less screened; for ζ exactly equal to 1 (but only in this case) $U(s \rightarrow \infty, \zeta = 1)$ goes to zero as s^{-2} .

Using the effective potential $U(s, \zeta)$ in the Overhauser scheme, we calculated the $\uparrow\downarrow$ high-density pair-correlation functions, $g_{\uparrow\downarrow}^{(1)}$, for different values of the spin-polarization ζ . They are shown in Fig. 3: the qualitative

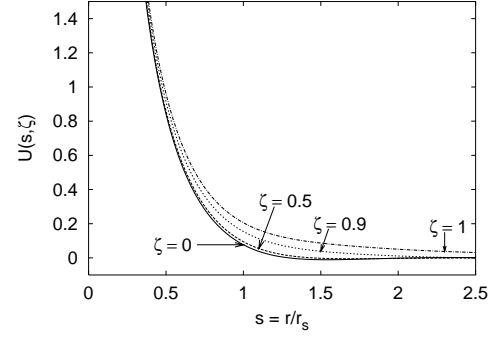


FIG. 2: ζ dependence of the dimensionless “dressed-dressed” potential $U(s, \zeta)$ calculated from Eq. (15).

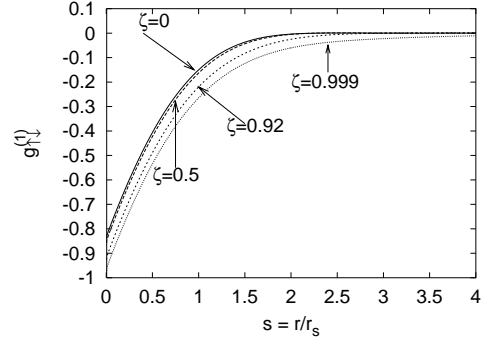


FIG. 3: High-density ($r_s \rightarrow 0$) $\uparrow\downarrow$ correlation holes computed from the “dressed-dressed” potential of Eq. (15) for different values of the spin polarization ζ .

behavior is very similar to the exact one of Fig. 1 of Rassolov *et al.*¹¹ This is more evident in our Fig. 1, where the function $\lambda(\zeta)/\lambda(0)$ is compared with the exact result.

While the ζ dependence of $g_{\uparrow\downarrow}^{(1)}(s, \zeta)$ obtained from the

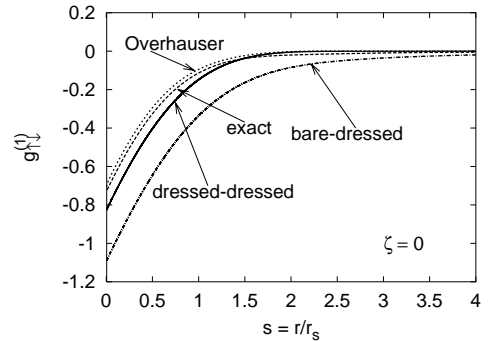


FIG. 4: High-density ($r_s \rightarrow 0$) $\uparrow\downarrow$ pair-correlation function for the $\zeta = 0$ gas obtained from different screened interactions: the “dressed-dressed” potential of Eq. (15), the original Overhauser potential of Eq. (8), and the “bare-dressed” potential of Eq. (20). The exact calculation of Rassolov *et al.*¹¹ is also reported.

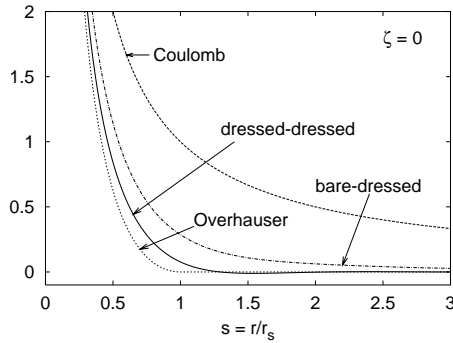


FIG. 5: Comparison of the bare Coulomb potential with different simple screened potentials for the $\zeta = 0$ gas in the high-density ($r_s \rightarrow 0$) limit: the “bare-dressed” potential of Eq. (20), the “dressed-dressed” potential of Eq. (15), and the original Overhauser potential of Eq. (8). All curves have been multiplied by r_s .

simple potential $U(s, \zeta)$ is rather good, the quantitative agreement with the exact result when $\zeta = 0$ is less accurate than the result obtained with the original Overhauser potential. This is shown in Fig. 4: we see that for small s , $g_{\uparrow\downarrow}^{(1)}$ obtained with $U(s, \zeta)$ of Eq. (15) is too deep, while the original Overhauser potential of Eq. (8) gives a result which is slightly less deep than the exact one. This means that the original Overhauser potential of Eq. (8) is slightly too screened in the $r_s \rightarrow 0$ limit, while $U(s, \zeta = 0)$ of Eq. (15) is not screened enough in the same limit. The “exact” effective potential for the high-density limit should thus lie in between the two curves “Overhauser” and “dressed-dressed” of Fig. 5. In the same figure we also show the bare Coulomb potential, and the “bare-dressed” potential (obtained from the interaction of a “bare” electron with a “dressed” electron, i.e., surrounded by its exchange hole), whose Fourier transform $\tilde{V}_1(k, r_s, \zeta)$ is

$$\tilde{V}_1(k, r_s, \zeta) = \frac{4\pi}{k^2} + v_1(k, r_s, \zeta), \quad (20)$$

where v_1 is given in Eq. (16). The “bare-dressed” potential is “philosophically” closer to the original picture of Overhauser^{3,7} and to the high-density limit of the self-consistent Hartree approximation of Davoudi *et al.*¹⁴ We see that the “bare-dressed” potential is much less screened than the “dressed-dressed” one and thus corresponds to a deeper (i.e., further from the exact result) $g_{\uparrow\downarrow}^{(1)}$, as shown in Fig. 4.

The “bare-dressed” potential encounters severe problems for the calculation of $\lambda(\zeta)/\lambda(0)$ of Fig. 1. When $\zeta \rightarrow 1$, each majority \uparrow electron dresses itself in an exchange hole deeper and more short-ranged than for $\zeta = 0$, while each minority \downarrow electron undresses. So the interaction between a bare \downarrow and a dressed \uparrow becomes *less* repulsive as ζ increases from 0, reducing $\lambda(\zeta)/\lambda(0)$. If we try to symmetrize using the interaction of a hypothetical bare \uparrow with a dressed \downarrow , we find that this interaction tends to the unscreened $1/r$ as $\zeta \rightarrow 1$.

Conclusions – We have proposed a simple “dressed-dressed” picture for the effective screened electron-electron interaction that shapes the geminals and thus the pair distribution function of a many-electron system. In this picture, the interaction is between two neutral objects, each an electron dressed by its exchange-correlation hole. For two electrons of opposite spin in a high-density electron gas of arbitrary spin polarization, where the “dressed-dressed” and “bare-dressed” interactions can be evaluated exactly, we have shown that the “dressed-dressed” picture is qualitatively correct. In future work, it may be possible to construct the “dressed-dressed” $V_{\sigma\sigma'}(r)$ for all r_s and ζ , using density functional theory^{1,2} to describe the additional exchange-correlation terms that arise when $\sigma' = \sigma$ or $r_s \gg 0$.

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